



Specifications

sp3 Model 665 HF CVD Diamond Deposition Reactor

General

Diamond Morphology: Polycrystalline diamond structure can be controlled to produce nanocrystalline or microcrystalline films from 500nm to 50um thick

Deposition Chamber:

Chamber size:	Two each 58.5 cm (23") Inside Diameter
Filament area:	Two each 38.1 cm x 35.6 cm (15" x 14")
Useful Deposition Area:	Two each 33 cm x 30 cm (13" x 12")

Power consumption: 70 kW max

Process Control

Recipe control:

- Automatic control via discrete recipe steps.
- Up to 59 steps.
- All parameters adjustable in each step.
- Real-time display of all parameters.
- Datalogging of all parameters.
- Manual control for maintenance and troubleshooting.
- Ethernet interface for:
 - recipe development
 - recipe management
 - data file access.

Gas control:

- 3 MFC-controlled process gas loops
 - H₂ 10 SLM
 - CH₄ 200 SCCM
 - N₂ 20 SLM
- 2 additional gas loops available as options.

Pressure control:

- Operating range 6 to 50 Torr
- Cycle time – 30 minute pump down, 10 minute vent
- Leak test – recipe controlled, optional on every run
- Downstream closed loop throttle valve control

Temperature monitoring:

- Chamber thermocouples (3 each chamber) - 35° to 1000° C
- Filament optical pyrometer (1 each chamber) - 800° to 3000° C
- Chamber Lid thermocouple (1 each chamber) – 15° to 90° C

Filament power

- 200 Volts DC, 150 Amps max (each chamber)

Facilities Requirements

Footprint:	Main Frame 122 cm x 168 cm (48" x 66") Control Rack 52 cm x 97 cm (21" x 38 ") Power Distribution Box 18 cm x 51 cm x 61 cm (7" x 20" x 24")
Height:	190 cm (74.5") max
Weight:	1000 Kg (2200 lbs)
Power input:	
Primary power:	480 VAC, 3 phase, 4 wire, 120 A or 380 VAC, 3 phase, 4 wire, 160 A
Vacuum pump:	208/220 VAC, 3 phase, 4 Wire, 15 amp
Cooling water:	20 gpm at 40 psi drop, 25° C maximum Requires ~50kW cooling capacity under normal operation Water must be treated – see separate recommendation
Access:	60 cm clearance all sides (24")
Process gasses:	H ₂ (99.995%), CH ₄ (99.9%) and N ₂ (15 to 20 psi)
Pneumatic control:	CDA (70 psi min)
Vacuum Pump:	Required 47 CFM minimum
Vac Exhaust Dilution:	<i>Customer responsibility according to local code/regulations</i>

Operating Environment

Temperature:	16° C to 24° C
Relative Humidity:	30-60% non-condensing

User Interface

Graphical User interface displays system operational status, provides system monitoring and control, data logging and recipe development and storage.

Safety – CE Compliant

Hardware interlocks: Equipment and personnel protected from hazardous situations related to flammable gas, high voltages and high temperatures. (Customer supplied external flammable gas detector required.)

Alarm Name	Interlock or Function	Device or Limits
Vacuum High	Main Vacuum Valve Closed	>50 Torr Nominal
Main Vacuum Valve Closed	No H2, CH4 flows, No Fil V.	Switch
Pump Dilution	No H2, No CH4 flows	Flow sensor
Vacuum Low	No Filament Voltage	<5 Torr Nominal
H2 Leak Detector	No H2, No CH4 flows	External Input
Low water Flow	No Filament Voltage	Flow Sensor
Pneumatic CDA Gas Cabinet Scavenge	No H2, CH4 flows, No Fil V.	CDA <60 psi Exhaust dilution interlock Scavenge air <150 CFM

Software interlocks: User controlled through Alarm/Abort Levels on analog values and status of digital alarm inputs.



